

VLMS333.., VLMR333.., VLMC333.., VLMY333..

Vishay Semiconductors

AUTOMOTIVE

COMPLIANT GREEN (5-2008)**

Power SMD LED PLCC-2



DESCRIPTION

The VLM.333.. series is an advanced modification of the Vishay VLM.31.. series. It is designed to incorporate larger chips, therefore, capable of withstanding a 50 mA drive current.

The package of the VLM.333.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED

• Product series: SMD Power

Package: PLCC-2

Angle of half intensity: ± 60°

FEATURES

- Utilizing latest advanced AllnGaP technology
- Available in 8 mm tape
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit $I_{Vmax}/I_{Vmin.} \le 1.6$
- Thermal resistance R = 400 K/W
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- Preconditioning: acc. to JEDEC level 2a
- Compatible with reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- AEC-Q101 qualified
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishav.com/applications

APPLICATIONS

- Traffic signals and signs
- · Interior and exterior lighting
- · Dashboard illumination
- Indicator and backlighting purposes for audio, video, LCDs switches, symbols, illuminated advertising etc

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMS333T2V2-GS08	Super red, I _V = (355 to 1120) mcd	AllnGaP on Si
VLMS333T2V2-GS18	Super red, I _V = (355 to 1120) mcd	AllnGaP on Si
VLMR333U1AA-GS08	Red, I _V = (450 to 1400) mcd	AllnGaP on Si
VLMR333U1AA-GS18	Red, I _V = (450 to 1400) mcd	AllnGaP on Si
VLMK333U2AB-GS08	Amber, I _V = (560 to 1800) mcd	AllnGaP on Si
VLMK333U2AB-GS18	Amber, I _V = (560 to 1800) mcd	AllnGaP on Si
VLMO333U2AB-GS08	Soft orange, I _V = (560 to 1800) mcd	AllnGaP on Si
VLMO333U2AB-GS18	Soft orange, I _V = (560 to 1800) mcd	AllnGaP on Si
VLMY333U1AA-GS08	Yellow, I _V = (450 to 1400) mcd	AllnGaP on Si
VLMY333U1AA-GS18	Yellow, I _V = (450 to 1400) mcd	AllnGaP on Si

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

Document Number 82383 Rev. 1.0, 19-Jul-10

VLMS333.., VLMR333.., VLMK333.., VLMO333.., VLMY333.. VISHAY.

Vishay Semiconductors



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) VLM.333							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage 1)	Short term application only	V _R	5	V			
DC Forward current	T _{amb} ≤ 73 °C (400 K/W)	I _F	50	mA			
Power dissipation		P _V	130	mW			
Junction temperature		Tj	125	°C			
Operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Thermal resistance junction/ ambient	Mounted on PC board (pad size > 16 mm ²)	R _{thJA}	400	K/W			

Note:

 $^{^{1)}\ \}mathrm{Driving}$ the LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) VLMS333, SUPER RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMS333T2V2	Ι _V	355	550	1120	mcd
Luminous flux/luminous intensity			ϕ_V/I_V		3		mlm/mcd
Dominant wavelength	I _F = 20 mA		λ _d	626	630	639	nm
Peak wavelength	I _F = 20 mA		λ_{p}		639		nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ		18		nm
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V_{F}	1.8	2	2.6	V
Reverse current	V _R = 5 V		I _R		0.01	10	μΑ

OPTICAL AND ELECTF VLMR333, RED	RICAL CHARACTERI	STICS (T _{amb} =	25 °C, unle	ess other	rwise spe	ecified)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMR333U1AA	I _V	450	750	1400	mcd
Luminous flux/luminous intensity			φ _V /I _V		3		mlm/mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	619	625	631	nm
Peak wavelength	I _F = 20 mA		λ_{p}		632		nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ		18		nm
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V_{F}	1.8	2	2.6	V
Reverse current	V _R = 5 V		I _R		0.01	10	μΑ





OPTICAL AND ELECTIVE VLMK333, AMBER	RICAL CHARACTERI	STICS (T _{amb} =	25 °C, unl	ess othe	rwise spe	ecified)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	VLMK333U2AB	I _V	560	850	1800	mcd
Luminous flux/luminous intensity			ϕ_V/I_V		3		mlm/mcd
Dominant wavelength	I _F = 20 mA		λ _d	611	616	622	nm
Peak wavelength	I _F = 20 mA		λ_{p}		622		nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ		18		nm
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F	1.8	2.1	2.6	V
Reverse current	V _R = 5 V		I _R		0.01	10	μΑ

OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) VLMO333, SOFT ORANGE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	VLMO333U2AB	I _V	560	950	1800	mcd
Luminous flux/luminous intensity			ϕ_V/I_V		3		mlm/mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	600	605	611	nm
Peak wavelength	I _F = 20 mA		λ_{p}		611		nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ		17		nm
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V_{F}	1.8	2.1	2.6	V
Reverse current	V _R = 5 V		I _R		0.01	10	μΑ

OPTICAL AND ELECTR VLMY333, YELLOW	ICAL CHARACTERI	STICS (T _{amb} =	25 °C, unl	less othe	rwise sp	ecified)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	VLMY333U1AA	Ι _V	450	750	1400	mcd
Luminous flux/luminous intensity			ϕ_V/I_V		3		mlm/mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	583	589	594	nm
Peak wavelength	I _F = 20 mA		λ_{p}		591		nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ		17		nm
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F	1.8	2.15	2.6	V
Reverse current	V _R = 5 V		I _R		0.01	10	μΑ

VLMS333.., VLMR333.., VLMK333.., VLMO333.., VLMY333.. VISHAY

Vishay Semiconductors



COLOR CLASS	COLOR CLASSIFICATION						
			DOMINANT	WAVELENGTH (nm)		
GROUP	AM	BER	SOFT (DRANGE	YELLOW		
	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
1	611	618					
2	614	622	600	603	583	586	
3			602	605	585	588	
4			604	607	587	590	
5			606	609	589	592	
6			608	611	591	594	

Note:

Wavelengths are tested at a current pulse duration of 25 ms.

LUMINOUS INTENSITY CLASSIFICATION							
GROUP	LUMIN	LUMINOUS INTENSITY (mcd)					
STANDARD	OPTIONAL	OPTIONAL MIN. MAX.					
Т	2	355	450				
П	1	450	560				
U	2	560	710				
V	1	710	900				
V	2	900	1120				
А	Α	1120	1400				
А	В	1400	1800				

CROSSING TABLE						
VISHAY	OSRAM					
VLMS333T2V2	LS T67F-T2V2-1-1					
VLMR333U1AA	LR T67F-U1AA-1-1					
VLMK333U2AB	LA T67F-U2AB-24-1					
VLMO333U2AB	LO T67F-U2AB-24-1					
VLMY333U1AA	LY T67F-U1AA-36-1					

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

Vishay Semiconductors

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

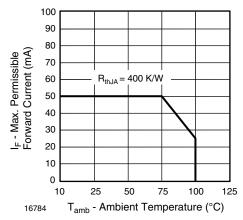


Figure 1. Max. Permissible Forward Current vs.
Ambient Temperature

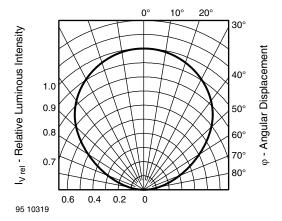


Figure 2. Rel. Luminous Intensity vs. Angular Displacement

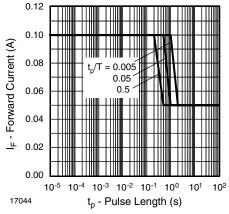


Figure 3. Forward Current vs. Pulse Length

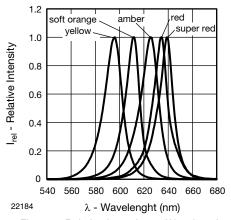


Figure 4. Relative Intensity vs. Wavelength

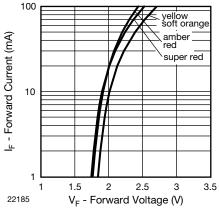


Figure 5. Forward Current vs. Forward Voltage

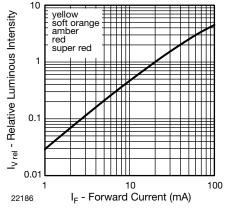


Figure 6. Relative Luminous Intensity vs. Forward Current

VLMS333.., VLMR333.., VLMO333.., VLMY333.. VISHAY

Vishay Semiconductors



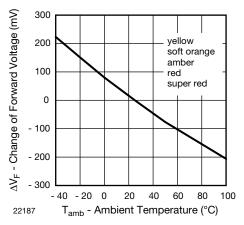


Figure 7. Change of Forward Voltage vs.
Ambient Temperature

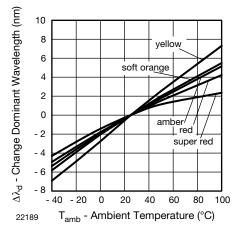


Figure 9. Change of Dominant Wavelength vs.

Ambient Temperature

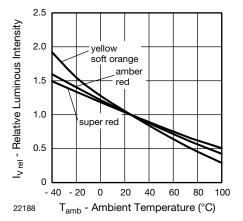
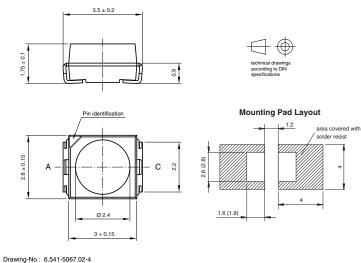


Figure 8. Relative Luminous Intensity vs. Amb. Temperature

PACKAGE DIMENSIONS in millimeters

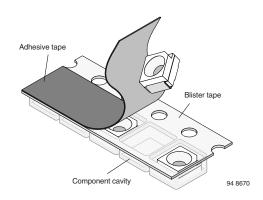


Vishay Semiconductors

METHOD OF TAPING/POLARITY AND TAPE AND REEL

SMD LED (VLMx333.. - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLMx333...

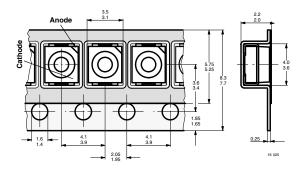


Figure 10. Tape Dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

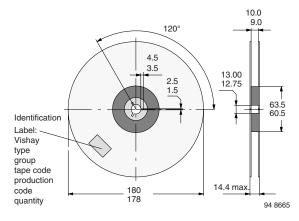


Figure 11. Reel Dimensions - GS08

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

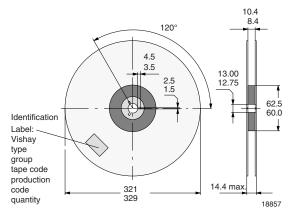


Figure 12. Reel Dimensions - GS18

VLMS333.., VLMR333.., VLMK333.., VLMO333.., VLMY333.. VISHAY

Vishay Semiconductors

VISHAY.

SOLDERING PROFILE

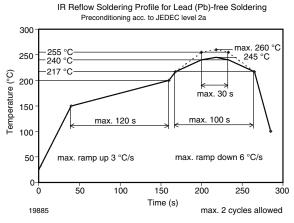


Figure 13. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

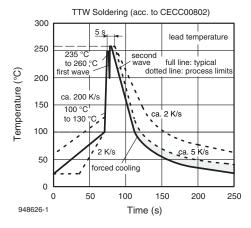
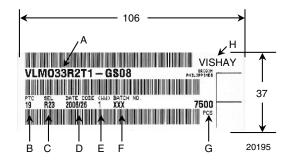


Figure 14. Double Wave Soldering of Opto Devices (all Packages)

BAR CODE PRODUCT LABEL EXAMPLE:



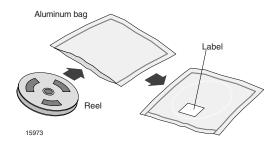
- A) Type of component
- B) Manufacturing plant
- C) SEL selection code (bin):
 - e.g.: R2 = code for luminous intensity group 3 = code for color group
- D Date code year/week
- E) Day code (e.g. 1: Monday)
- F) Batch no.
- G) Total quantity
- H) Company code

VLMS333.., VLMR333.., VLMK333.., VLMO333.., VLMY333..

Vishay Semiconductors

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

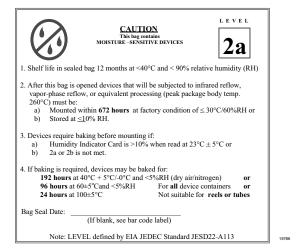
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 $^{\circ}$ C + 5 $^{\circ}$ C and < 5 $^{\circ}$ RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC Standard JESD22-A112 Level 2a label is included on all dry bags.



Example of JESD22-A112 Level 2a Label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar-code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

Document Number 82383 Rev. 1.0, 19-Jul-10



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.